



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of  
SOWLATI ET AL

Atty. Docket  
US 000099

RECEIVED 2811  
JUL -5 2001  
TC 2800 MAIL ROOM

Application No. 09/545,785

Group Art Unit: 2811

Filed: April 7, 200

Examiner: O. Nadav

For: INTERDIGITATED MULTILAYER CAPACITOR STRUCTURE FOR DEEP SUB-MICRON CMOS

AMENDMENT and RESPONSE under 37 C.F.R. § 1.111

Assistant Commissioner for Patents  
Washington, D.C. 20231

6/a  
FJONES  
7-9-01

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Assistant Commissioner for Patents, Washington, D.C. 20231

On: June 21, 2001  
By: Elissa De Lucca

Sir:

In response to the Office action dated March 23, 2001, please amend the above referenced application as follows and reconsider the application in light of the following remarks.

In the Claims:

Per 37 CFR § 1.121(c)(1)(i), please rewrite claims 1, 5,

Subt B' and 6 as follows.

1. (Amended) A capacitor comprising:  
a first level of at least four electrically conductive

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